Notice of References Cited Application/Control No. 10/042,181 Examiner Bradley K Smith Applicant(s)/Patent Under Reexamination BOJARCZUK ET AL. Page 1 of 1

U.S. PATENT DOCUMENTS

		Danimant Number	Data		
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FOREIGN PATENT DOCUMENTS

*		Document Number Country Code-Number-Kind Code	Date MM-YYYY	Country	Name	Classification
	N					
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NON-PATENT DOCUMENTS

*		Include as applicable: Author, Title Date, Publisher, Edition or Volume, Pertinent Pages)
	υ	Chon et al. "Fatigue free samarium-modified bismuth titanate film capacitors having large spontaneous polarizations", November Applied Physics Letters, volume 79 number 10 pages 3137-3139
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A copy of this reference is not being furnished with this Office action. (See MPEP § 707.05(a).) Dates in MM-YYYY format are publication dates. Classifications may be US or foreign.